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|  | <h2 style="color: red;">IRF8707GTRPBF</h2> | |
| | Hersteller-Teilenummer: | IRF8707GTRPBF |
|  | Hersteller / Marke: | International Rectifier (Infineon Technologies) |
| | Teil der Beschreibung: | MOSFET N-CH 30V 11A 8-SOIC |
| Datenblätter: |  IRF8707GTRPBF.pdf | |
| RoHs Status: | Bleifrei / RoHS-konform | |
| Lagerzustand: | New original, 97712 pcs Stock Available. | |
| Liefern von: | Hong Kong | |
| Versandweg: | DHL/Fedex/TNT/UPS/EMS | |
| Image may be representation. See specs for product details. | | |

Spezifikationen

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|--|---|
| Teilenummer | IRF8707GTRPBF |
| Hersteller | International Rectifier (Infineon Technologies) |
| Beschreibung | MOSFET N-CH 30V 11A 8-SOIC |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 97712 pcs Stock |
| Serie | HEXFET® |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | 8-SOIC (0.154", 3.90mm Width) |
| Supplier Device-Gehäuse | 8-SO |
| Verlustleistung (max) | 2.5W (Ta) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 30V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 11A (Ta) |
| Rds On (Max) @ Id, Vgs | 11.9 mOhm @ 11A, 10V |
| VGS (th) (Max) @ Id | 2.35V @ 25µA |
| Gate Charge (Qg) (Max) @ Vgs | 9.3nC @ 4.5V |
| Eingabekapazität (Ciss) (Max) @ Vds | 760pF @ 15V |
| Antriebsspannung (Max Rds On, Min Rds On) | 4.5V, 10V |
| Vgs (Max) | ±20V |
| Verpackung | Tape & Reel (TR) |

IRF8707GTRPBF ist neu im Original, Suche IRF8707GTRPBF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IRF8707GTRPBF International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IRF8707GTRPBF: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|--|--|---|
|  <p>IRF8513PBF International Rectifier (Infineon Technologies) MOSFET 2N-CH 30V 8A/11A 8-SOIC</p> |  <p>IRF8513TRPBF. IR IRF8513TRPBF. IR</p> |  <p>IRF8513TRPBF International Rectifier (Infineon Technologies) MOSFET 2N-CH 30V 8A/11A 8-SOIC</p> |  <p>IRF8707PBF-1 IR IRF8707PBF-1 IR</p> |
|  <p>IRF8707GTRPBF. IR IRF8707GTRPBF. IR</p> |  <p>IRF8707GPBF International Rectifier (Infineon Technologies) MOSFET N-CH 30V 11A 8-SOIC</p> |  <p>IRF8707HTRPBF IR IRF8707HTRPBF IR</p> |  <p>IRF8707PBF International Rectifier (Infineon Technologies) MOSFET N-CH 30V 11A 8-SOIC</p> |

heiße Teile

Mehr

- | | | | | |
|--|---|--|---|---|
|  IRF840LCLPBF |  IRF840LCLPBF |  IRF840LCPBF | D IRF840LCPBF |  IRF840LCSPBF |
|  IRF840LCSPBF |  IRF840LCSTRL | D IRF840LCSTRL |  IRF840LCSTRRPBF |  IRF840LCSTRRPBF |
|  IRF840NS |  IRF840NSTRPBF |  IRF840PBF |  IRF840PBF |  IRF840STRPBF |
| D IRF840STRRPBF |  IRF840STRRPBF |  IRF841FI |  IRF841PBF |  IRF842PBF |
|  IRF843PBF |  IRF8513PBF |  IRF8513TRPBF |  IRF8513TRPBF. |  IRF8707GPBF |
|  IRF8707GTRPBF. |  IRF8707HTRPBF | D IRF8707PBF |  IRF8707PBF-1 |  IRF8707TRPBF |
|  IRF8707TRPBF. | D IRF8714GTRPBF |  IRF8714GTRPBF. |  IRF8714TR |  IRF8714TRPBF |
|  IRF8714TRPBF. |  IRF8721GTPBF |  IRF8721GTRPBF |  IRF8721GTRPBF. |  IRF8721TRPBF |
|  IRF8721TRPBF. |  IRF8734TRPBF |  IRF8736PBF | D IRF8736TR |  IRF8736TRPBF |
|  IRF8788TRPBF |  IRF8852TRPBF |  IRF8910G |  IRF8910GTRPBF |  IRF8910GTRPBF. |

Contact us:Info@Y-IC.com

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